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Serial Number: 10687744

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## PALM INTRANET

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## **Inventor Information for 10/687744**

Inventor Name	City	State/Country
CHEN, CHO YING	TAICHUNG	TAIWAN
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US 20060059675 A1	20060323	Method for manufacturing zippers	29/408		Hsieh; Chen- Chou
US 20050279805 A1	20051222	Bondhead for wire bonding apparatus	228/4.5	228/44.7	Wong, Yam Mo et al.
US 20050266208 A1	20051201	Abrasion-resistant, antistatic, antireflective transparent coating and method for making it	428/143		Raychaudhuri, Satyabrata et al.
US 20050160207 A1	20050721	Computing apparatus including a hardware management add- on card	710/74	710/301	Chen, Chong- Kuang et al.
US 20050124111 A1	20050609	Method for forming a self-aligned buried strap in a vertical memory cell	438/241	257/E21.008; 438/386	Huang, Cheng-Chih et al.
US 20050124110 A1	20050609	METHOD FOR FORMING A SELF-ALIGNED BURIED STRAP IN A VERTICAL MEMORY CELL	438/241	257/301; 257/E21.008; 257/E29.346; 438/386	Huang, Cheng-Chih et al.
US 20050110102 A1	20050526	Method for forming oxide on ONO structure	257/411	257/E21.21; 257/E21.268; 257/E21.423	
US 20050088348 A1	20050428	Driven arrray dual-band linear antenna	343/702		Chi, Hsiang- Jung et al.
US 20050066453 A1	20050331	Photochromic dye	8/635		Chiu, Jen-Yi et al.
US 20050064643 A1	20050324	Method for isolation layer for a vertical DRAM	438/202		Huang, Cheng-Chih et al.
US 20050062842 A1	20050324	Videoconferencing service system, videoconferencing service operating method and	348/14.08	348/14.11	Yang, Yuefeng et al.

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		service center			
US 20050020028 A1	20050127	Method for fabricating trench isolation	438/439	257/E21.548	Liao, Chien- Mao et al.
US 20050014608 A1	20050120	Handle capable of detecting human physiological characteristics for exercise apparatus	482/8	482/1	Chen, Choa- Chuan
US 20040228789 A1	20041118	Method of controlling swelling and shrinkage during synthesis of coke	423/445R		Stiller, Alfred et al.
US 20040225263 A1	20041111	Syringe with a snapping device for backward pulling the needle into the syringe after syringing	604/228		Chen, Cho Ying
US 20040204509 A1	20041014	Preparation of homogeneously loaded ion exchangers	521/25		Bollinger, Mark A. et al.
US 20040175877 A1	20040909	Method of forming a bottle-shaped trench	438/200		Lin, Shian- Jyh et al.
US 20040139782 A1	20040722	Clamp calibration apparatus and method	73/1.01		Chen, Chong Hao et al.
US 20040099605 A1	20040527	High performance continuous reaction/separation process using a continuous liquid-solid contactor	210/657		Chiang, Chen- Chou et al.
US 20040082921 A1	20040429	Infusion port apparatus of a vascular infusion assembly	604/246		Chen, Cho Ying
US 20040075835 A1	20040422	Method of inspecting grain size of a polysilicon film	356/369		Lin, Kun- Chih et al.
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A1		composition			
US	20040401	High performance	560/1		Chiang, Chen-
20040063992		continuous		1	Chou et al.
Al		reaction/separation			
		process using a			
		continuous liquid-			
		solid contactor			
US	20040304	Apparatus and	118/724	156/345.53	Lu, Kuo-
20040040509	20010301	method for			Liang et al.
A1		preventing etchant			
		condensation on			
		wafer in a cooling			
		chamber			
US	20040219	High performance	210/656		Chiang, Chen-
20040031757	20040219	continuous	210,030		Chou et al.
A1		reaction/separation	!		
Ai		process using a			
		continuous liquid-			
	:	solid contactor			
US	20040129	Process for the	568/728		Chiang, Chen-
20040019241	20040127	production of	300,720		Chou et al.
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US	20031204	Shower tubing for	134/34	134/199;	Yang, Shin-
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20030085415	20030308	sensor device	2377232		Yao et al.
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1		making arumma			
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US	20030313	MAKING AN	730/200		Yao et al.
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TIC	20021226	Method for	438/48	438/73	Chen, Chong-
US	20021220	fabricating a	טריטנד	130/73	Yao et al.
20020197758		CMOS image			
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Al	20021212	sensor	438/292	257/E27.132	Chen, Chong-
US	20021219	STRUCTURE OF	430/292	Z311EZ1.13Z	Chen, Chong-

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20020192913	,	A CMOS IMAGE	·		Yao et ai.
A1	,	SENSOR AND	1		
J	,	METHOD FOR	1		
1	, ]	FABRICATING	(		
		THE SAME	-55/200	255707 122	Ol Olema
US	20021219	STRUCTURE OF	257/290	257/E27.132	Chen, Chong-
20020190286	i J	A CMOS IMAGE	1		Yao et al.
A1		SENSOR	<b></b>		
US	20021107	Wet dip method	134/19	134/30;	Ma, Ching-
20020162578	ı J	for photoresist and	1	216/91;	Tien et al.
A1	ı l	polymer stripping	1	257/E21.228;	1
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US	20020314	Method for	438/682	257/E21.438;	Chen, Chong-
20020031910		integrating anti-	1	257/E31.12;	Yao et al.
A1	1	reflection layer	1	257/E31.121	1
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US 7074700	20060711	Method for	438/593	438/268;	Huang;
B2	20000.11	isolation layer for	,50.2.	438/270;	Cheng-Chih et
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US 7045057	20060516	Preparation of	210/140	210/189;	Bollinger;
B2 /043037	20000510	homogeneously	210/110	210/268;	Mark A. et al.
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,	,	excitatigets	,	210/284,	1
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i			1	521/29;	
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US 7025243	20060411	Bondhead for wire	228/4.5	228/180.5	Wong; Yam
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1		strap in a vertical		438/248;	
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B2		fabricating trench		438/435;	Mao et al.
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US 6948387	20050927	Clamp calibration	73/862.541	73/1.08	Chen, Chong

		method			
US 6933416 B2	20050823	Process for the production of bisphenol-A	568/728		Chiang; Chen- Chou et al.
US 6927123 B2	20050809	Method for forming a self- aligned buried strap in a vertical memory cell	438/249	257/E21.008; 257/E29.346; 438/244; 438/246; 438/247; 438/387; 438/389; 438/390; 438/392	Huang; Cheng-Chih et al.
US 6922243 B2	20050726	Method of inspecting grain size of a polysilicon film	356/369		Lin; Kun- Chih et al.
US 6906364 B2	20050614	Structure of a CMOS image sensor	257/292	257/291; 257/294	Chen; Chong- Yao et al.
US 6835641 B1	20041228	Method of forming single sided conductor and semiconductor device having the same	438/597	438/243; 438/244; 438/386; 438/584	Yang; Sweehan J. H. et al.
US 6770125 B2	20040803	Reversible thermochromic composition	106/31.18		Chen; Peen- Taurn et al.
US 6656165 B2	20031202	Disposable safety syringe	604/240	604/110	Chen; Cho- Yin
US 6652666 B2	20031125	Wet dip method for photoresist and polymer stripping without buffer treatment step	134/30	134/19; 134/38; 134/902; 257/E21.228; 257/E21.255	Ma; Ching- Tien et al.
US 6607951 B2	20030819	Method for fabricating a CMOS image sensor	438/199	257/232; 257/290; 257/369; 438/200; 438/229; 438/275; 438/299; 438/48; 438/57	Chen; Chong- Yao et al.
US 6599270	20030729	Syringe with a	604/110	<u> </u>	Chen; Cho

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B1		snapping device for backward pulling the needle into the syringe after syringing			Ying
US 6541329 B1	20030401	Method for making an active pixel sensor	438/237	438/200; 438/232; 438/306	Chen; Chong- Yao et al.
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US 6506619 B2	20030114	Structure of a CMOS image sensor and method for fabricating the same	438/48	257/E27.132; 438/199; 438/253; 438/70	Chen; Chong- Yao et al.
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US 6313338 B1	20011106	Process for preparing N-[1-(S)-ethyoxycarbonyl-3-phenylpropyl]-L-ananine N-carboxyanhydride	560/24		Chen; Chong- Ming et al.
US 6303406 B1	20011016	Method for integrating anti-reflection layer and salicide block	438/72	257/E21.438; 257/E31.12; 257/E31.121; 438/636; 438/64; 438/69; 438/70	Chen; Chong- Yao et al.
US 6302948 B1	20011016	Textile ink-jet printing-purpose disperse dye micro-emulsion agent	106/31.37	106/31.43; 106/31.47; 106/31.58	Lin; Cheng Kun et al.
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US 6152773 A	20001128	Electrical connector having reliably secured shield	439/607		Chen; Cho- Hsu
US 5903279 A	19990511	Method for antialiasing	345/443		Lee; Chi-Chih et al.
US 5580151 A	19961203	Warning light mounting assembly	362/549	248/215; 248/311.2; 362/191; 362/396; 362/398; 362/542	Chen; Chow-
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A		connector			Lin et al.
US 5472354	19951205	Electrical	439/357	439/65	Chen; Chou
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